Single-chip built-in FET type Switching Regulator Series

High Efficiency Step-down Switching Regulator

BD9161FVM

●Description

ROHM's high efficiency step-down switching regulator BD9161FVM is a power supply designed to produce 1.2volts (low voltage) from 3.3volts power supply line. Offers high efficiency with our original pulse skip control technology and synchronous rectifier. Employs a current mode control system to provide faster transient response to sudden change in load.

●Features

1) Offers fast transient response with current mode PWM control system.
2) Offers highly efficiency for all load range with synchronous rectifier (Nch/Pch FET)
3) Incorporates 100% Duty function.
4) Incorporates soft-start function.
5) Incorporates thermal protection and ULVO functions.
6) Incorporates short-current protection circuit with time delay function.
7) Incorporates shutdown function Icc=0μA (Typ.)
8) Employs small surface mount package MSOP8

●Use

Power supply for HDD, DVS and for LSI of CPU, ASIC

●Absolute Maximum Rating (Ta=25℃)

Parameter	Symbol	Limits	Unit
		BD9161FVM	
VCC voltage	VCC	-0.3～+7 *1	V
PVCC voltage	PVCC	-0.3～+7 *1	V
EN Voltage	EN	-0.3～+7	V
SW, ITH Voltage	SW,ITH	-0.3～+7	V
Power Dissipation 1	Pd1	387.5*2	mW
Power Dissipation 2	Pd2	587.4*3	mW
Power Dissipation 3	Topr	-25～+85	℃
Power Dissipation 4	Tstg	-55～+150	℃
EN voltage	Tjmax	+150	℃

∗1 Pd should not be exceeded.
∗2 Derating in done 3.1mW/℃ for temperatures above Ta=25℃.
∗3 Derating in done 4.7mW/℃ for temperatures above Ta=25℃,Mounted on 70mm×70mm×1.6mm Glass Epoxy PCB.

●Operating Conditions (Ta=25℃)

Parameter	Symbol	BD9161FVM			Unit
		Min.	Typ.	Max.	
VCC voltage	VCC*4	2.5	3.3	4.5	V
PVCC voltage	PVCC*4	2.5	3.3	4.5	V
EN voltage	EN	0	-	VCC	V
Output Voltage Setting Range	SW,ITH	1.0	-	3.3	V
SW, ITH average output current	Isw*4	-	-	0.6	A

∗4 Pd should not be exceeded.

Dec. 2008

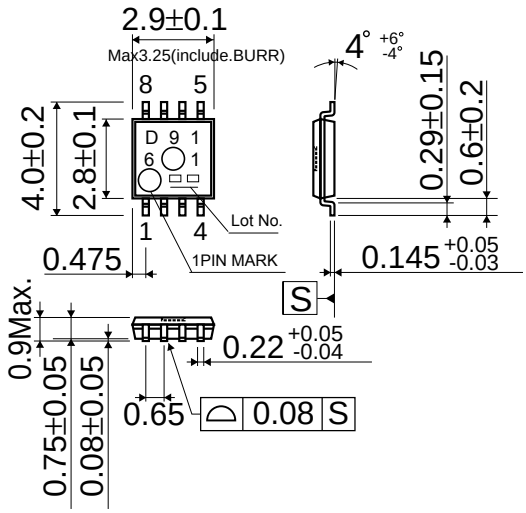
●Electrical Characteristics

◎BD9161FVM (Ta=25℃, VCC=PVCC=3.3V, EN=VCC, unless otherwise specified.)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Standby current	ISTB	-	0	10	μA	EN=GND
Bias current	ICC	-	200	400	μA	
EN Low voltage	VENL	-	GND	0.8	V	Standby mode
EN High voltage	VENH	2.0	VCC	-	V	Active mode
EN input current	IEN	-	1	10	μA	VEN=3.3V
Oscillation frequency	FOSC	0.8	1	1.2	MHz	
Pch FET ON resistance	RONP	-	0.35	0.6	Ω	PVCC=3.3V
Nch FET ON resistance	RONN	-	0.37	0.68	Ω	PVCC=3.3V
Output voltage	VOUT	0.784	0.8	0.816	V	
ITH sink current	ITHSI	10	20	-	μA	VOUT =H
ITH source current	ITHSO	10	20	-	μA	VOUT =L
UVLO threshold voltage	VUVLO1	2.2	2.3	2.4	V	VCC=H→L
UVLO hysteresis voltage	VUVLO2	2.22	2.35	2.5	V	VCC=L→H
Soft start time	TSS	0.5	1	2	ms	
Timer latch time	TLATCH	1	2	3	ms	SCP/TSD operated
Output Short circuit Threshold Voltage	VSCP	-	0.4	0.56	V	VOUT =H→L

●Block Diagram, Application Circuit

【BD9161FVM】



MSOP8 (Unit:mm)

Fig.1 BD9161FVM Dimension

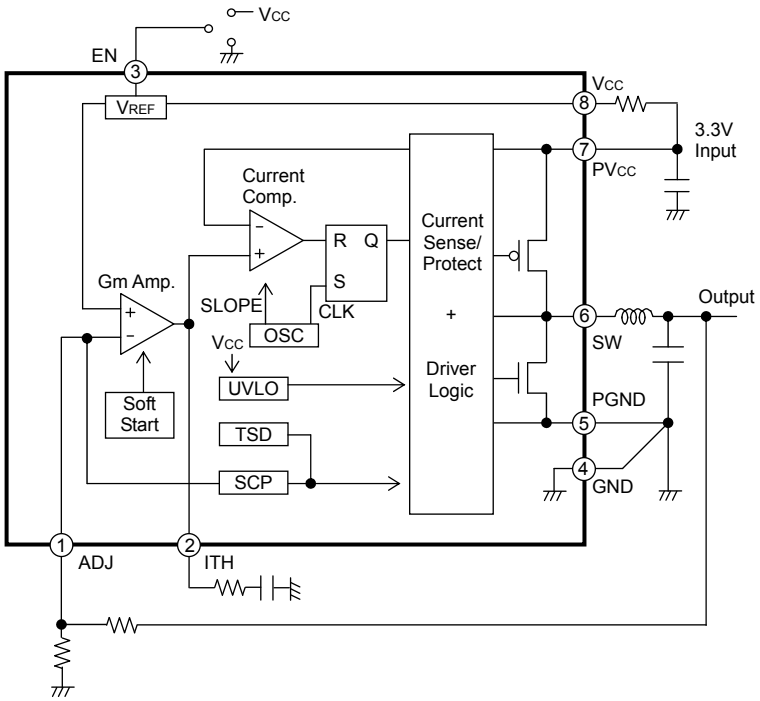


Fig.2 BD9161FVM Block Diagram

●Pin No. & function table

Pin No.	Pin name	PIN function
1	ADJ	Output voltage Feedback pin (Adjustable)
2	ITH	GmAmp output pin/Connected phase compensation capacitor
3	EN	Enable pin (Active High)
4	GND	Ground
5	PGND	Nch FET source pin
6	SW	Pch/Nch FET drain output pin
7	PVCC	Pch FET source pin
8	VCC	VCC power supply input pin

●Characteristics data【BD9161FVM】

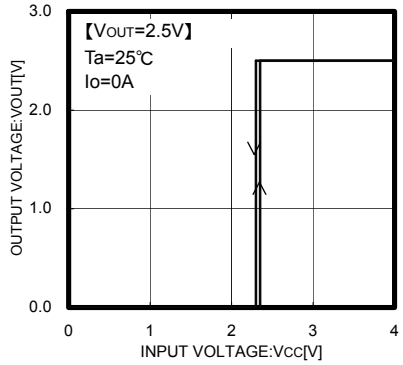


Fig.3 VCC-VOUT

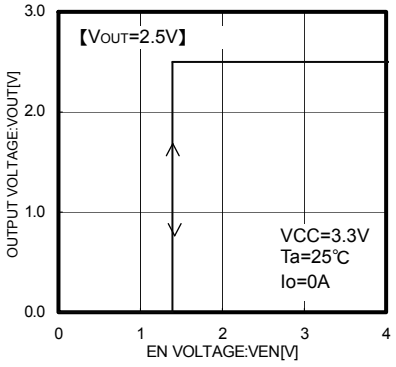


Fig.4 VEN-VOUT

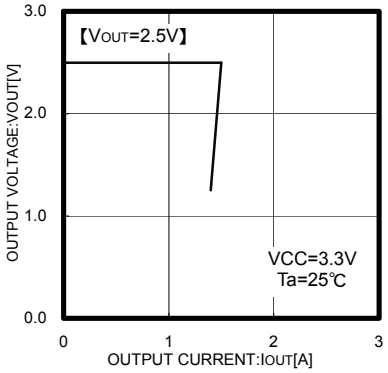


Fig.5 IOUT-VOUT

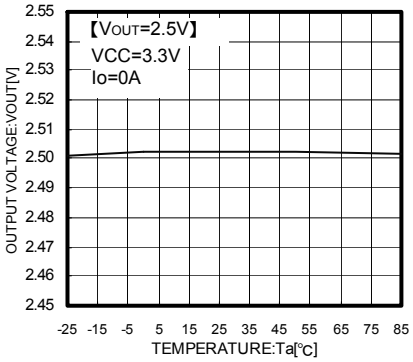


Fig. 6 Ta-VOUT

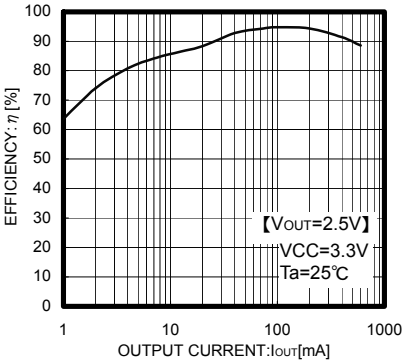


Fig.7 Efficiency

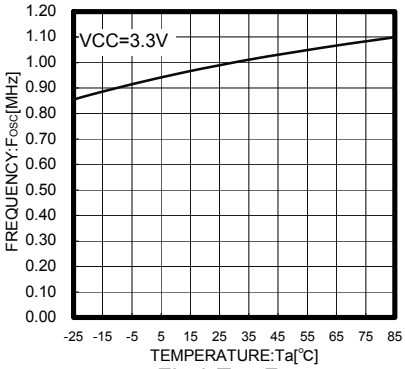


Fig.8 Ta - Fosc

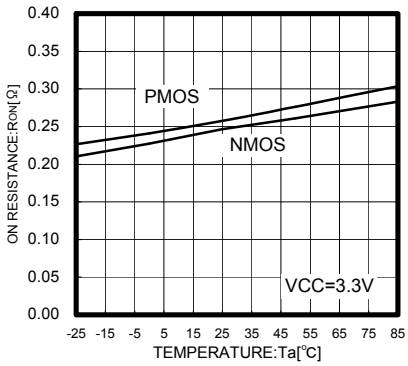


Fig.9 Ta-VEN

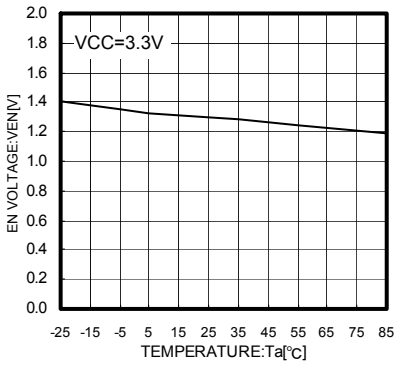


Fig.10 Ta-ICC

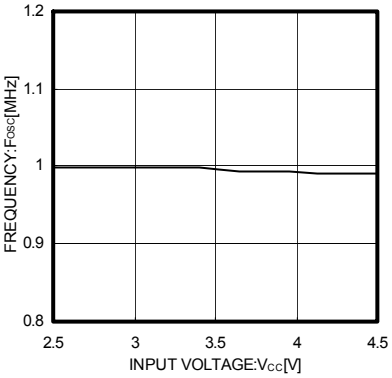


Fig.11 VCC-FOSC

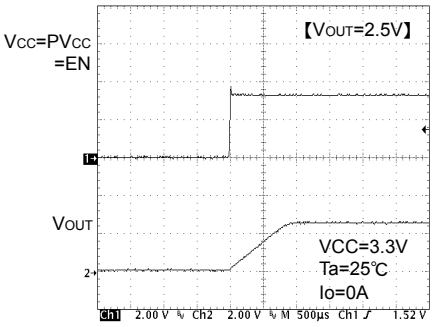


Fig.12 Soft start waveform

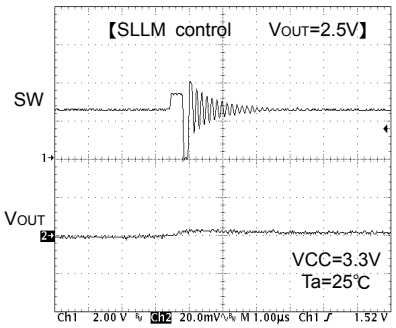


Fig.13 SW waveform Io=10mA

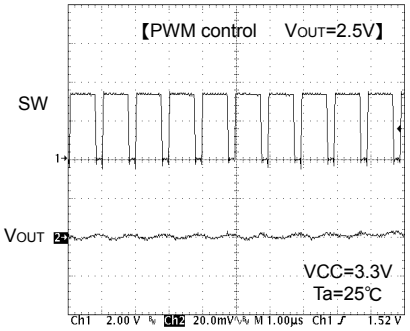


Fig.14 SW waveform Io=500mA

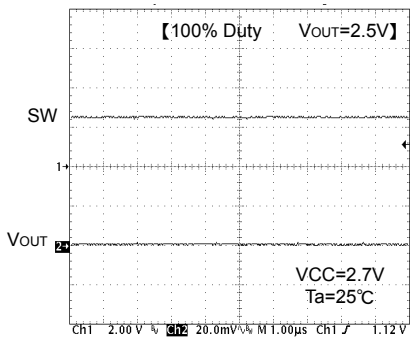


Fig. 15 SW waveform Io=600mA

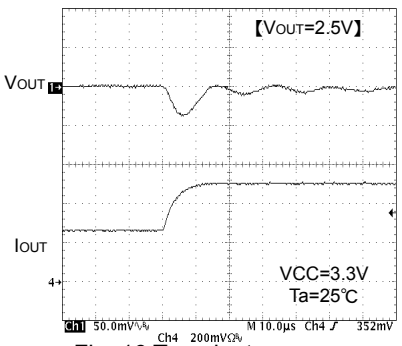


Fig. 16 Transient response
Io=250→500mA(10μs)

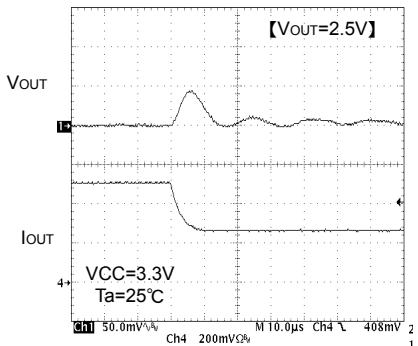
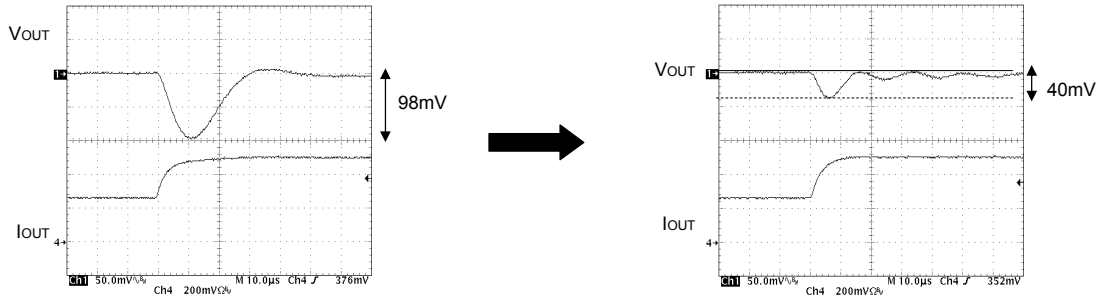


Fig.17 Transient response
Io=500→250mA(10μs)

●Information on advantages

Advantage 1：Offers fast transient response with current mode control system.

Conventional product (VOUT of which is 2.5 volts)　　BD9161FVM (Load response IO=250mA→500mA)



Voltage drop due to sudden change in load was reduced by about 50%.

Fig.18 Comparison of transient response

Advantage 2：Offers high efficiency for all load range.

・For lighter load:

Utilizes the current mode control mode called SLLM for lighter load, which reduces various dissipation such as switching dissipation (P_{SW}), gate charge/discharge dissipation, ESR dissipation of output capacitor (P_{ESR}) and on-resistance dissipation (P_{RON}) that may otherwise cause degradation in efficiency for lighter load.

↓

Achieves efficiency improvement for lighter load.

・For heavier load:

Utilizes the synchronous rectifying mode and the low on-resistance MOS FETs incorporated as power transistor.

{ ON resistance of P-channel MOS FET: 0.35 Ω (Typ.)
{ ON resistance of N-channel MOS FET: 0.37 Ω (Typ.)

↓

Achieves efficiency improvement for heavier load.

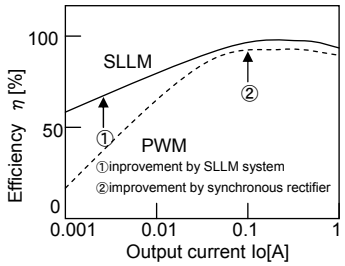


Fig.19 Efficiency

Offers high efficiency for all load range with the improvements mentioned above.

Advantage 3：・Supplied in smaller package due to small-sized power MOS FET incorporated.
・Allows reduction in size of application products

↓

Reduces a mounting area required.

{ ・Output capacitor Co required for current mode control: 10 μF ceramic capacitor
{ ・Inductance L required for the operating frequency of 1 MHz: 4.7 μH inductor

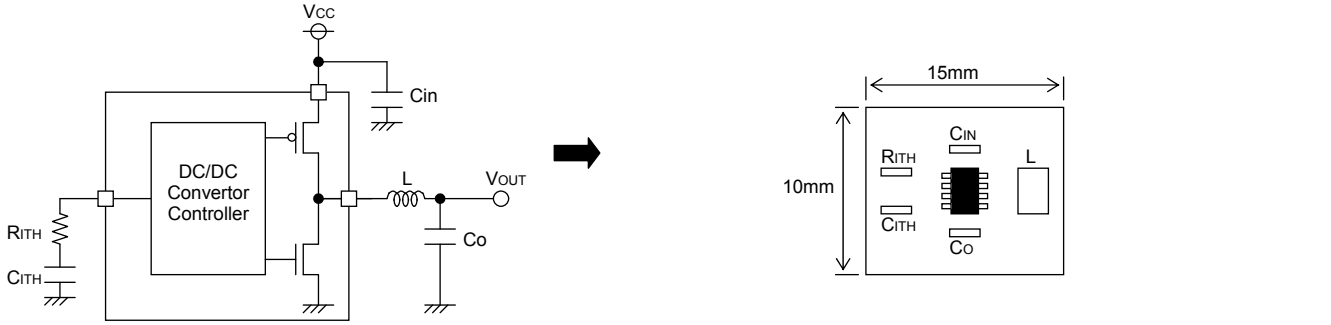


Fig.20 Example application

●Operation

BD9161FVM is a synchronous rectifying step-down switching regulator that achieves faster transient response by employing current mode PWM control system. It utilizes switching operation in PWM (Pulse Width Modulation) mode for heavier load, while it utilizes SLLM (Simple Light Load Mode) operation for lighter load to improve efficiency.

○Current mode PWM control

Synthesizes a PWM control signal with a inductor current feedback loop added to the voltage feedback.

・PWM (Pulse Width Modulation) control

The oscillation frequency for PWM is 1 MHz. SET signal form OSC turns ON a P-channel MOS FET (while a N-channel MOS FET is turned OFF), and an inductor current I_L increases. The current comparator (Current Comp) receives two signals, a current feedback control signal (SENSE: Voltage converted from I_L) and a voltage feedback control signal (FB), and issues a RESET signal if both input signals are identical to each other, and turns OFF the P-channel MOS FET (while a N-channel MOS FET is turned ON) for the rest of the fixed period. The PWM control repeats this operation.

・SLLM™ (Simple Light Load Mode) control

When the control mode is shifted from PWM for heavier load to the one for lighter load or vise versa, the switching pulse is designed to turn OFF with the device held operated in normal PWM control loop, which allows linear operation without voltage drop or deterioration in transient response during the mode switching from light load to heavy load or vise versa.

Although the PWM control loop continues to operate with a SET signal from OSC and a RESET signal from Current Comp, it is so designed that the RESET signal is held issued if shifted to the light load mode, with which the switching is tuned OFF and the switching pulses are thinned out under control. Activating the switching intermittently reduces the switching dissipation and improves the efficiency.

・100% Duty control

Max duty is 100%. (@ Pch MOS FET always ON) In usual PWM control, in case output voltage cannot keep (ex, drop of input voltage), oscillation frequency becomes lower and finally it becomes 100% duty. The output voltage is a value that depends only by on a voltage hang from the input voltage to Pch MOS FET, and can keep the output voltage even with the low input voltage.

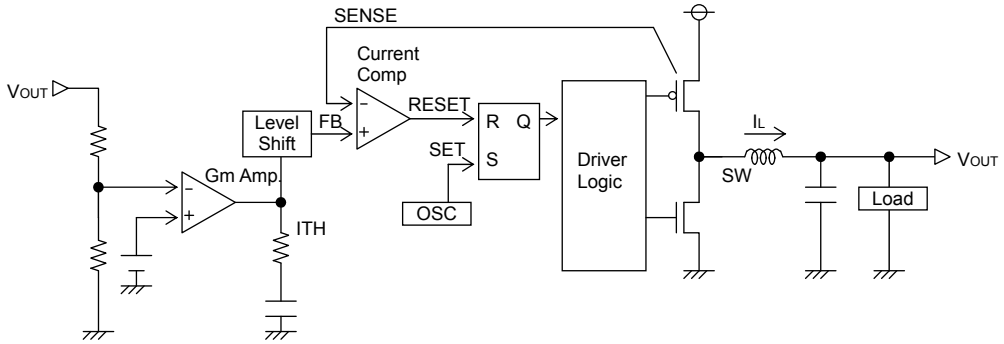


Fig.21 Diagram of current mode PWM control

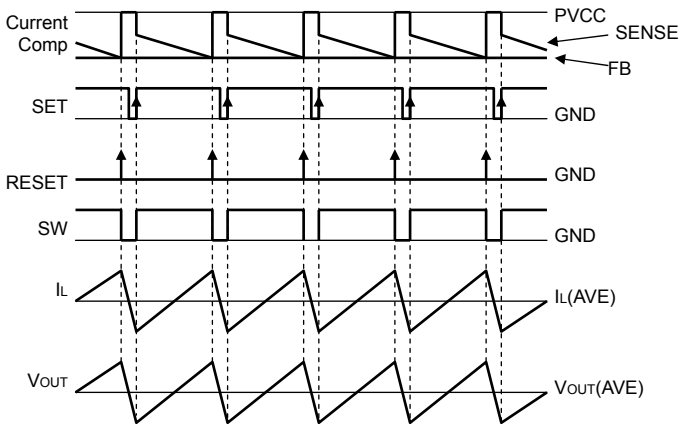


Fig.22 PWM switching timing chart

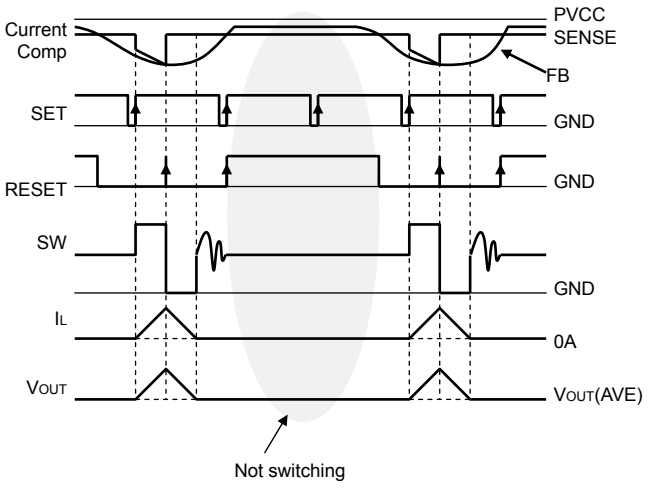


Fig.23 SLLM™ switching timing chart

●Description of operations

・Soft-start function

EN terminal shifted to “High” activates a soft-starter to gradually establish the output voltage with the current limited during startup, by which it is possible to prevent an overshoot of output voltage and an inrush current.

・Shutdown function

With EN terminal shifted to “Low”, the device turns to Standby Mode, and all the function blocks including reference voltage circuit, internal oscillator and drivers are turned to OFF. Circuit current during standby is 0μF (Typ.).

・UVLO function

Detects whether the input voltage sufficient to secure the output voltage of this IC is supplied. And the hysteresis width of 50 mV (Typ.) is provided to prevent output chattering.

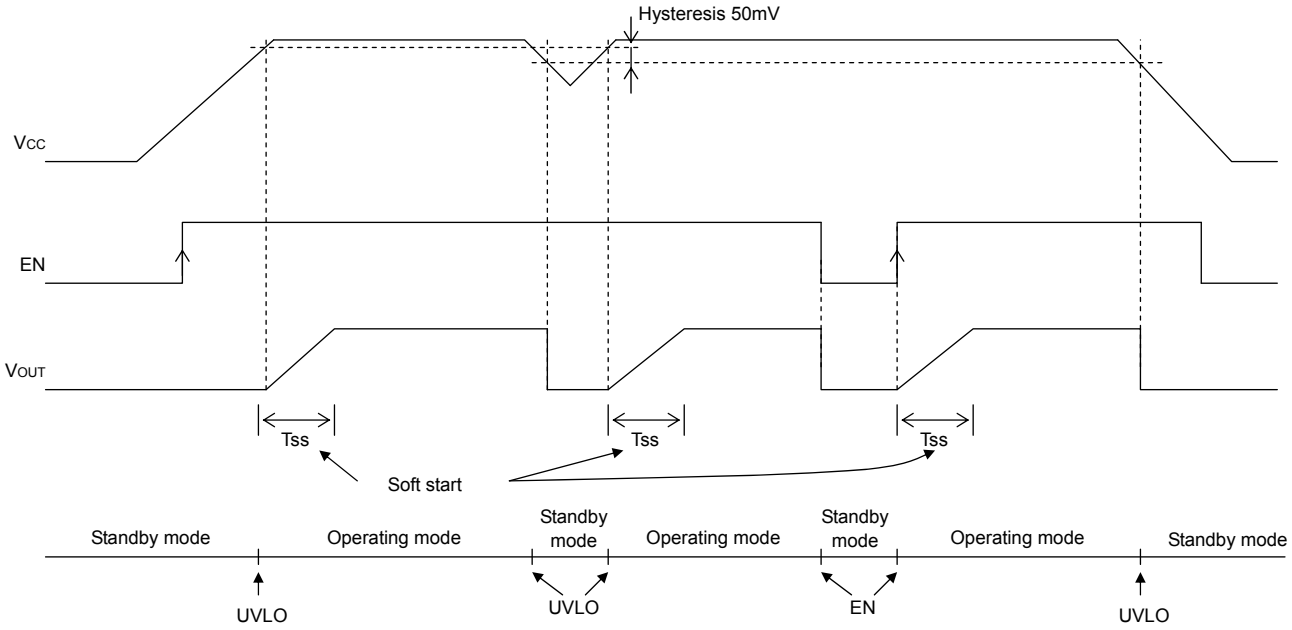


Fig.24 Soft start, Shutdown, UVLO timing chart

・Short-current protection circuit with time delay function

Turns OFF the output to protect the IC from breakdown when the incorporated current limiter is activated continuously for the fixed time (T_{LATCH}) or more. The output thus held tuned OFF may be recovered by restarting EN or by re-unlocking UVLO.

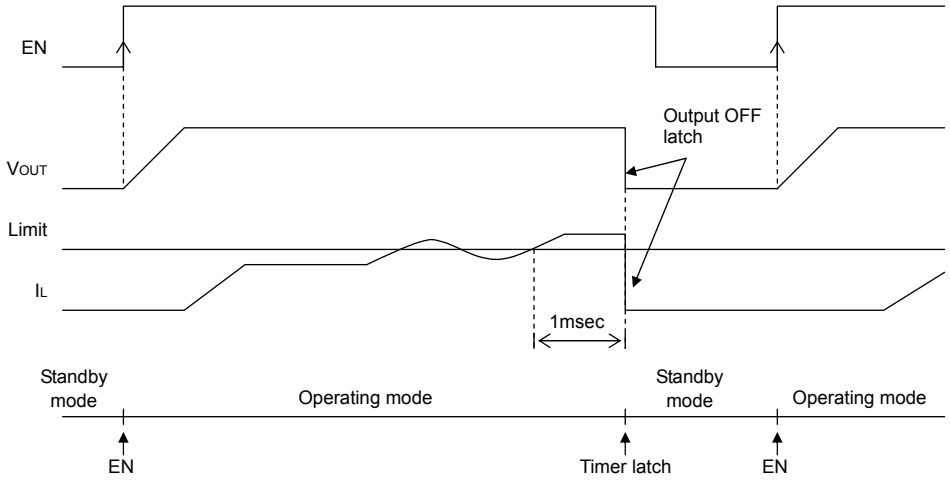


Fig.25 Short-current protection circuit with time delay timing chart

●Switching regulator efficiency

Efficiency η may be expressed by the equation shown below:

$$\eta = \frac{V_{OUT} \times I_{OUT}}{Vin \times Iin} \times 100[\%] = \frac{P_{OUT}}{Pin} \times 100[\%] = \frac{P_{OUT}}{P_{OUT}+P_D \alpha} \times 100[\%]$$

Efficiency may be improved by reducing the switching regulator power dissipation factors $P_D\alpha$ as follows:

Dissipation factors:

1) ON resistance dissipation of inductor and FET : PD(I^2R)
2) Gate charge/discharge dissipation : PD(Gate)
3) Switching dissipation : PD(SW)
4) ESR dissipation of capacitor : PD(ESR)
5) Operating current dissipation of IC : PD(IC)

1)PD(I^2R)=$I_{OUT}^2 \times (R_{COIL}+R_{ON})$ (R_{COIL}[Ω] : DC resistance of inductor, R_{ON}[Ω] : ON resistance of FET
I_{OUT}[A] : Output current.)

2)PD(Gate)=Cgs×f×V (Cgs[F] : Gate capacitance of FET, f[H] : Switching frequency, V[V] : Gate driving voltage of FET)

3)PD(SW)= $\frac{Vin^2 \times C_{RSS} \times I_{OUT} \times f}{I_{DRIVE}}$ (C_{RSS}[F] : Reverse transfer capacitance of FET, I_{DRIVE}[A] : Peak current of gate.)

4)PD(ESR)=$I_{RMS}^2 \times$ESR (I_{RMS}[A] : Ripple current of capacitor, ESR[Ω] : Equivalent series resistance.)

5)PD(IC)=Vin×I_{CC} (I_{CC}[A] : Circuit current.)

●Consideration on permissible dissipation and heat generation

As this IC functions with high efficiency without significant heat generation in most applications, no special consideration is needed on permissible dissipation or heat generation. In case of extreme conditions, however, including lower input voltage, higher output voltage, heavier load, and/or higher temperature, the permissible dissipation and/or heat generation must be carefully considered.

For dissipation, only conduction losses due to DC resistance of inductor and ON resistance of FET are considered. Because the conduction losses are considered to play the leading role among other dissipation mentioned above including gate charge/discharge dissipation and switching dissipation.

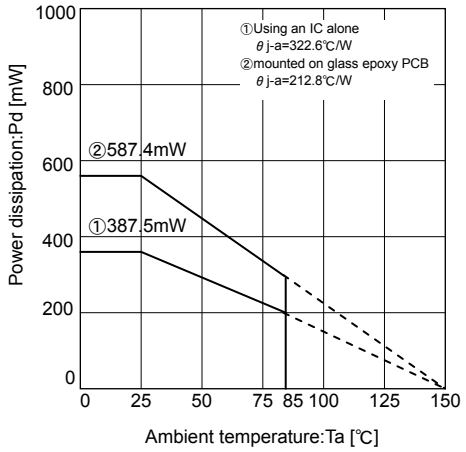


Fig.26 Thermal derating curve
(MSOP8)

$P=I_{OUT}^2 \times (R_{ON})$

$R_{ON}=D \times R_{ONP}+(1-D) \times R_{ONN}$

D：ON duty (=V_{OUT}/V_{CC})

R_{ONP}：ON resistance of P-channel MOS FET

R_{ONN}：ON resistance of N-channel MOS FET

I_{OUT}：Output current

If V_{CC}=3.3V, V_{OUT}=2.5V R_{ONP}=0.35Ω, R_{ONN}=0.37Ω

I_{OUT}=0.6A, for example,

$D=V_{OUT}/V_{CC}=2.5/3.3=0.758$

$R_{ON}=0.758 \times 0.35+(1-0.758) \times 0.37$

$=0.2653+0.08954$

$=0.35484[\Omega]$

$P=0.6^2 \times 0.35484$

$\fallingdotseq 127.7[mV]$

As R_{ONP} is greater than R_{ONN} in this IC, the dissipation increases as the ON duty becomes greater. With the consideration on the dissipation as above, thermal design must be carried out with sufficient margin allowed.

●Selection of components externally connected

1. Selection of inductor (L)

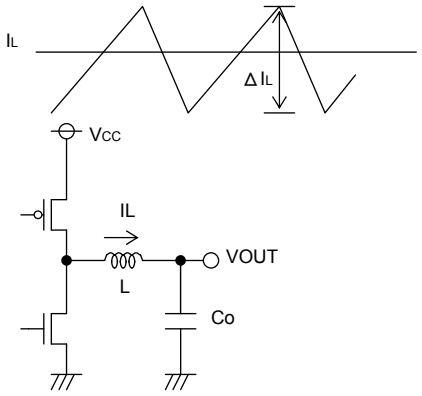


Fig.27 Output ripple current

The inductance significantly depends on output ripple current. As seen in the equation (1), the ripple current decreases as the inductor and/or switching frequency increases.

$$\Delta I_L = \frac{(V_{CC}-V_{OUT})\times V_{OUT}}{L\times V_{CC}\times f}\ [A]\ \cdot\ \cdot\ \cdot (1)$$

Appropriate ripple current at output should be 20～30% more or less of the maximum output current.

$$\Delta I_L = 0.25\times I_{OUT}max.\ [A]\ \cdot\ \cdot\ \cdot (2)$$

$$L = \frac{(V_{CC}-V_{OUT})\times V_{OUT}}{\Delta I_L\times V_{CC}\times f}\ [H]\ \cdot\ \cdot\ \cdot (3)$$

(ΔIL: Output ripple current, and f: Switching frequency)

*Current exceeding the current rating of the inductor results in magnetic saturation of the inductor, which decreases efficiency. The inductor must be selected allowing sufficient margin with which the peak current may not exceed its current rating.

If V_{CC}=3.3V, V_{OUT}=2.5V, f=1MHz, $\Delta I_L = 0.25\times 0.6A = 0.15A$

$$L \geqq \frac{(3.3-2.5)\times 2.5}{0.15\times 3.3\times 1M} \geqq 4.04\mu$$

*Select the inductor of low resistance component (such as DCR and ACR) to minimize dissipation in the inductor for better efficiency.

2. Selection of output capacitor (Co)

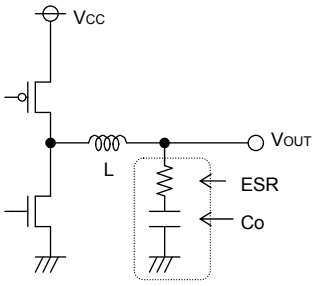


Fig.28 Output capacitor

Output capacitor should be selected with the consideration on the stability region and the equivalent series resistance required to smooth ripple voltage.
Output ripple voltage is determined by the equation (4) :

$$\Delta V_{OUT} = \Delta I_L \times ESR\ [V]\ \cdot\ \cdot\ \cdot (4)$$

(ΔIL: Output ripple current, ESR: Equivalent series resistance of output capacitor)

*Rating of the capacitor should be determined allowing sufficient margin against output voltage. Less ESR allows reduction in output ripple voltage.

Inappropriate capacitance may cause problem in startup. A 10μF to 100μF ceramic capacitor is recommended.

3. Selection of input capacitor (Cin)

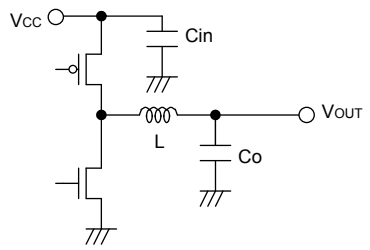


Fig.29 Input capacitor

Input capacitor to select must be a low ESR capacitor of the capacitance sufficient to cope with high ripple current to prevent high transient voltage. The ripple current IRMS is given by the equation (5):

$$I_{RMS}=I_{OUT}\times\frac{\sqrt{V_{OUT}(V_{CC}-V_{OUT})}}{V_{CC}}\ [A]\ \cdot\ \cdot\ \cdot\ (5)$$

< Worst case > $I_{RMS(max.)}$

When VCC is twice the Vout, $I_{RMS}=\frac{I_{OUT}}{2}$

If V_{CC}=3.3V, V_{OUT}=2.5V, and $I_{OUTmax.}$=0.6A

$$I_{RMS}=0.6\times\frac{\sqrt{2.5(3.3-2.5)}}{5}=0.284[A_{RMS}]$$

A low ESR 10μF/10V ceramic capacitor is recommended to reduce ESR dissipation of input capacitor for better efficiency.

4. Determination of RITH, CITH that works as a phase compensator

As the Current Mode Control is designed to limit a inductor current, a pole (phase lag) appears in the low frequency area due to a CR filter consisting of a output capacitor and a load resistance, while a zero (phase lead) appears in the high frequency area due to the output capacitor and its ESR. So, the phases are easily compensated by adding a zero to the power amplifier output with C and R as described below to cancel a pole at the power amplifier.

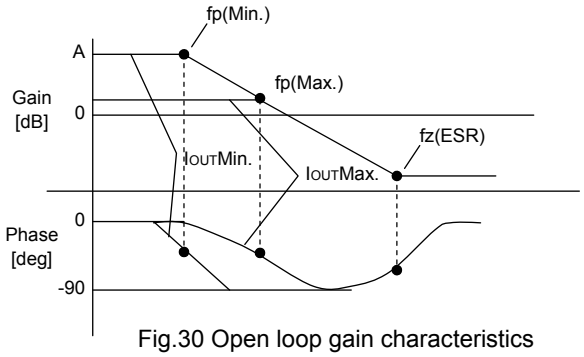


Fig.30 Open loop gain characteristics

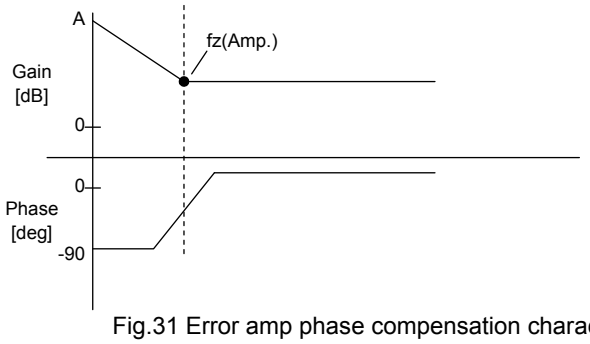


Fig.31 Error amp phase compensation characteristics

$$f_p=\frac{1}{2\pi\times R_O\times C_O}$$

$$f_{z(ESR)}=\frac{1}{2\pi\times E_{SR}\times C_O}$$

Pole at power amplifier

When the output current decreases, the load resistance Ro increases and the pole frequency lowers.

$$f_{p(Min.)}=\frac{1}{2\pi\times R_{OMax.}\times C_O}\ [Hz]\leftarrow\text{with lighter load}$$

$$f_{p(Max.)}=\frac{1}{2\pi\times R_{OMin.}\times C_O}\ [Hz]\leftarrow\text{with heavier load}$$

Zero at power amplifier

Increasing capacitance of the output capacitor lowers the pole frequency while the zero frequency does not change. (This is because when the capacitance is doubled, the capacitor ESR reduces to half.)

$$f_{z(Amp.)}=\frac{1}{2\pi\times R_{ITH.}\times C_{ITH}}$$

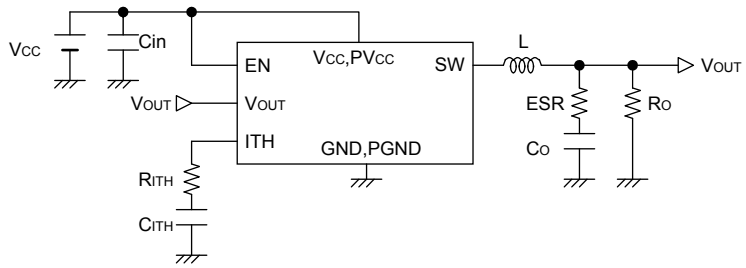


Fig.32 Typical application

Stable feedback loop may be achieved by canceling the pole fp (Min.) produced by the output capacitor and the load resistance with CR zero correction by the error amplifier.

$$fz(Amp.) = fp(Min.)$$

$$\longrightarrow \frac{1}{2\pi \times R_{ITH} \times C_{ITH}} = \frac{1}{2\pi \times R_{OMax.} \times C_O}$$

5. Determination of output voltage

The output voltage V_{OUT} is determined by the equation (6):

$V_{OUT}=(R2/R1+1)\times V_{ADJ}$ ・・・(6) V_{ADJ}: Voltage at ADJ terminal (0.8V Typ.)

With R1 and R2 adjusted, the output voltage may be determined as required.

(Adjustable output voltage range： 1.0V～3.3V)

Use 1 kΩ～100 kΩ resistor for R1. If a resistor of the resistance higher than 100 kΩ is used, check the assembled set carefully for ripple voltage etc.

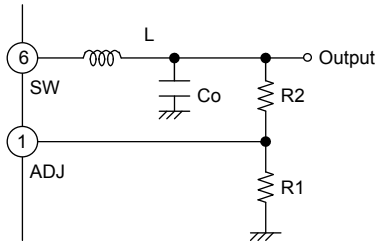


Fig.33 Determination of output voltage

●BD9161FVM　Cautions on PC Board layout

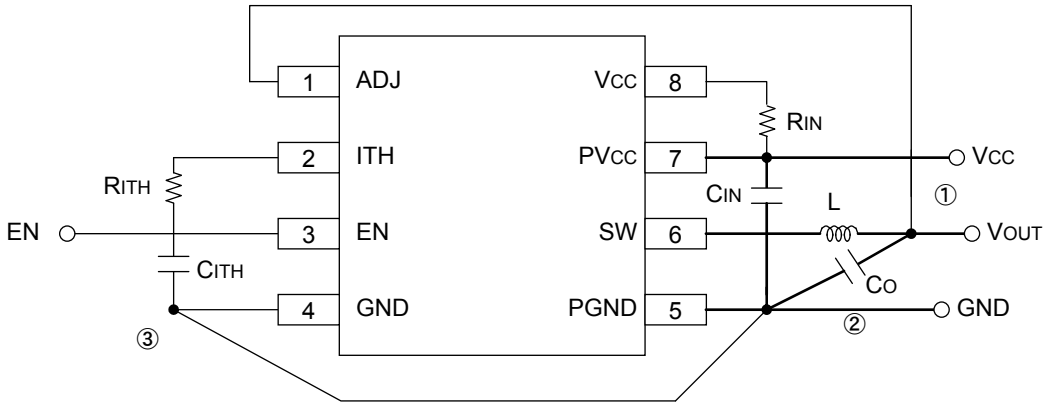


Fig.34 Board layout

① For the sections drawn with heavy line, use thick conductor pattern as short as possible.
② Lay out the input ceramic capacitor CIN closer to the pins PVCC and PGND, and the output capacitor Co closer to the pin PGND.
③ Lay out CITH and RITH between the pins ITH and GND as neat as possible with least necessary wiring.

●Recommended component lists with above applications

Table. [BD9161FVM]

Symbol	Part	Value		Manufacturer	Series
L	Coil	4.7μH		TDK	VLF5014AT-4R7M1R1
				Sumida	CMD6D11B
RIN	Resistance	10Ω		ROHM	MCR03 Series
CIN	Ceramic capacitor	10μF		Kyocera	CM316X5R106K10A
Co	Ceramic capacitor	10μF		Kyocera	CM316X5R106K10A
CITH	Ceramic capacitor	V_{OUT}=1.0V	820pF	murata	GRM18 Series
		V_{OUT}=1.2V	560pF	murata	GRM18 Series
		V_{OUT}=1.5V	470pF	murata	GRM18 Series
		V_{OUT}=1.8V	470pF	murata	GRM18 Series
		V_{OUT}=2.5V	330pF	murata	GRM18 Series
RITH	Resistance	V_{OUT}=1.0V	6.8kΩ	ROHM	MCR03 Series
		V_{OUT}=1.2V	8.2kΩ	ROHM	MCR03 Series
		V_{OUT}=1.5V	12kΩ	ROHM	MCR03 Series
		V_{OUT}=1.8V	12kΩ	ROHM	MCR03 Series
		V_{OUT}=2.5V	15kΩ	ROHM	MCR03 Series

*The parts list presented above is an example of recommended parts. Although the parts are sound, actual circuit characteristics should be checked on your application carefully before use. Be sure to allow sufficient margins to accommodate variations between external devices and this IC when employing the depicted circuit with other circuit constants modified. Both static and transient characteristics should be considered in establishing these margins. When switching noise is substantial and may impact the system, a low pass filter should be inserted between the VCC and PVCC pins, and a schottky barrier diode established between the SW and PGND pins.

●I/O equivalence circuit
【BD9161FVM】

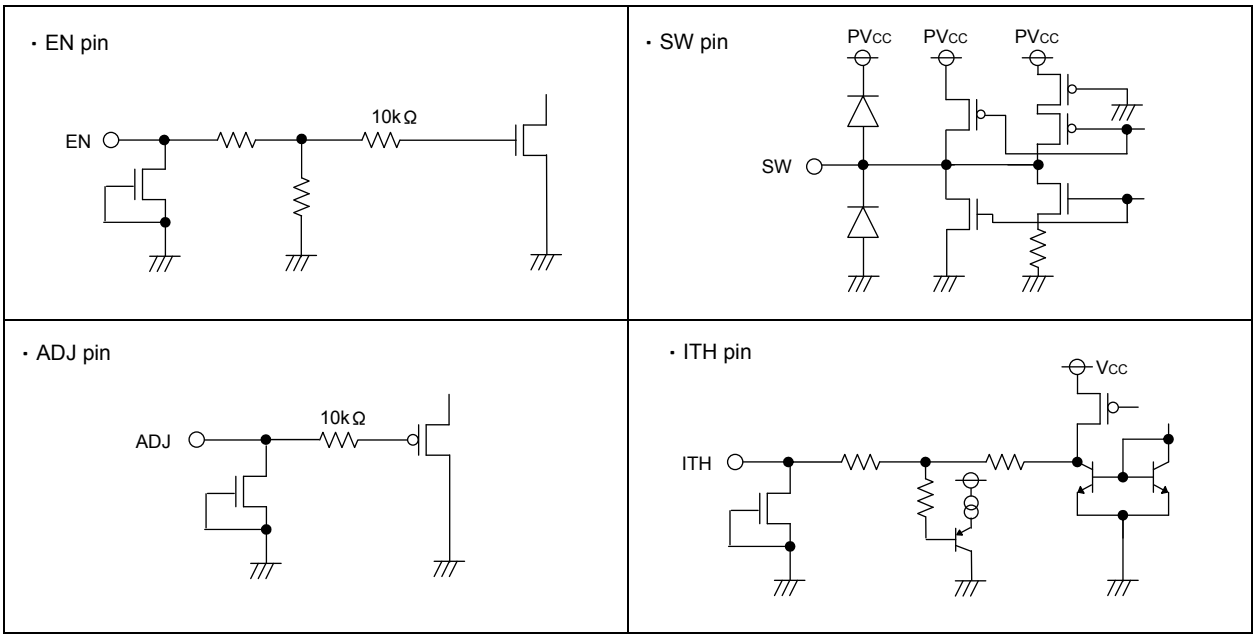


Fig.36 I/O equivalence circuit

●Cautions on use

1. Absolute Maximum Ratings

While utmost care is taken to quality control of this product, any application that may exceed some of the absolute maximum ratings including the voltage applied and the operating temperature range may result in breakage. If broken, short-mode or open-mode may not be identified. So if it is expected to encounter with special mode that may exceed the absolute maximum ratings, it is requested to take necessary safety measures physically including insertion of fuses.

2. Electrical potential at GND

GND must be designed to have the lowest electrical potential In any operating conditions.

3. Short-circuiting between terminals, and mismounting

When mounting to pc board, care must be taken to avoid mistake in its orientation and alignment. Failure to do so may result in IC breakdown. Short-circuiting due to foreign matters entered between output terminals, or between output and power supply or GND may also cause breakdown.

4.Operation in Strong electromagnetic field

Be noted that using the IC in the strong electromagnetic radiation can cause operation failures.

5. Thermal shutdown protection circuit

Thermal shutdown protection circuit is the circuit designed to isolate the IC from thermal runaway, and not intended to protect and guarantee the IC. So, the IC the thermal shutdown protection circuit of which is once activated should not be used thereafter for any operation originally intended.

6. Inspection with the IC set to a pc board

If a capacitor must be connected to the pin of lower impedance during inspection with the IC set to a pc board, the capacitor must be discharged after each process to avoid stress to the IC. For electrostatic protection, provide proper grounding to assembling processes with special care taken in handling and storage. When connecting to jigs in the inspection process, be sure to turn OFF the power supply before it is connected and removed.

7. Input to IC terminals

This is a monolithic IC with P^+ isolation between P-substrate and each element as illustrated below. This P-layer and the N-layer of each element form a P-N junction, and various parasitic element are formed.

If a resistor is joined to a transistor terminal as shown in Fig 37:

○P-N junction works as a parasitic diode if the following relationship is satisfied; GND>Terminal A (at resistor side), or GND>Terminal B (at transistor side); and

○if GND>Terminal B (at NPN transistor side),

a parasitic NPN transistor is activated by N-layer of other element adjacent to the above-mentioned parasitic diode.

The structure of the IC inevitably forms parasitic elements, the activation of which may cause interference among circuits, and/or malfunctions contributing to breakdown. It is therefore requested to take care not to use the device in such manner that the voltage lower than GND (at P-substrate) may be applied to the input terminal, which may result in activation of parasitic elements.

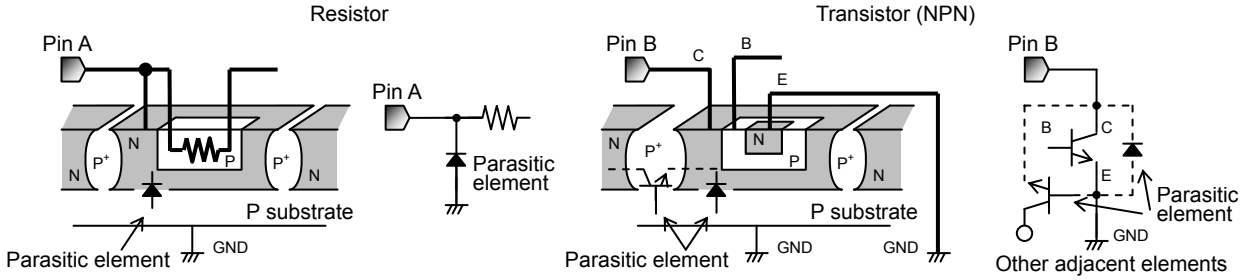


Fig.37 Simplified structure of monorisic IC

8. Ground wiring pattern

If small-signal GND and large-current GND are provided, It will be recommended to separate the large-current GND pattern from the small-signal GND pattern and establish a single ground at the reference point of the set PCB so that resistance to the wiring pattern and voltage fluctuations due to a large current will cause no fluctuations in voltages of the small-signal GND. Pay attention not to cause fluctuations in the GND wiring pattern of external parts as well.

●Ordering part number

B	D	9	1	6	1	F	V	M	−	T	R

ROHM part number

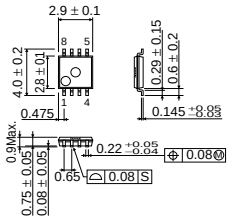
Type
61 : Adjustable (0.8~3.3V)

Package
FVM : MSOP8

Package specification
TR : Embossed taping

MSOP8

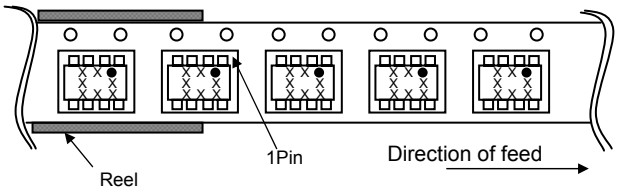
<Dimension>



(Unit:mm)

<Tape and Reel information>

Tape	Embossed carrier tape
Quantity	3000pcs
Direction of feed	TR (The direction is the 1pin of product is at the upper light when you hold reel on the left hand and you pull out the tape on the right hand)



※When you order , please order in times the amount of package quantity.

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ROHM CO., LTD.

21 Saiin Mizosaki-cho, Ukyo-ku, Kyoto
615-8585, Japan
TEL: +81-75-311-2121 FAX: +81-75-315-0172
URL http: // www. rohm. com

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TEL : +81-75-311-2121
FAX : +81-75-315-0172